NSN 5961-01-048-4720

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-048-4720 **Inclosure Material:** Metal **Overall Length:** 0.2 millimeters **Overall Height:** 0.1 millimeters **Overall Width:** 0.2 millimeters **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 forward voltage, average **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 25.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 flange Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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